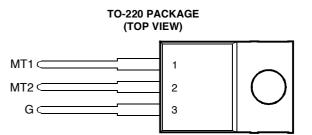
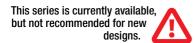
# BOURNS®



- Sensitive Gate Triacs
- 6 A RMS
- Glass Passivated Wafer
- 400 V to 800 V Off-State Voltage
- Max I<sub>GT</sub> of 5 mA (Quadrants 1 3)



Pin 2 is in electrical contact with the mounting base.



## absolute maximum ratings over operating case temperature (unless otherwise noted)

| RATING  |         |                  | VALUE       | UNIT |  |
|---|---------|------------------|-------------|------|--|
|   | TIC216D |                  | 400         |      |  |
| Repetitive peak off-state voltage (see Note 1)  | TIC216M | V                | 600         | v    |  |
|   | TIC216S | V <sub>DRM</sub> | 700         | v    |  |
|   | TIC216N |                  | 800         |      |  |
| Full-cycle RMS on-state current at (or below) 70°C case temperature (see Note 2)            |         |                  | 6           | А    |  |
| Peak on-state surge current full-sine-waveat (or below) 25°C case temperature (see Note 3)  |         |                  | 60          | А    |  |
| Peak gate current   |         |                  | ±1          | А    |  |
| Peak gate power dissipation at (or below) 85°C case temperature (pulse width $\leq$ 200 µs) |         |                  | 2.2         | W    |  |
| Average gate power dissipation at (or below) 85°C case temperature (see Note 4)             |         |                  | 0.9         | W    |  |
| Operating case temperature range  |         |                  | -40 to +110 | °C   |  |
| Storage temperature range   |         |                  | -40 to +125 | °C   |  |
| Lead temperature 1.6 mm from case for 10 seconds  |         |                  | 230         | °C   |  |

NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.

 This value applies for 50-Hz full-sine-wave operation with resistive load. Above 70°C derate linearly to 110°C case temperature at the rate of 150 mA/°C.

This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of on-state current. Surge
may be repeated after the device has returned to original thermal equilibrium. During the surge, gate control may be lost.

4. This value applies for a maximum averaging time of 20 ms.

#### electrical characteristics at 25°C case temperature (unless otherwise noted )

| PARAMETER        |                                      | TEST CONDITIONS  |  |  | MIN | ТҮР | MAX      | UNIT |
|------------------|--------------------------------------|--|--|--|-----|-----|----------|------|
| I <sub>DRM</sub> | Repetitive peak<br>off-state current | $V_D$ = rated $V_{DRM}$                                      | I <sub>G</sub> = 0                             | T <sub>C</sub> = 110°C                                 |     |     | ±2       | mA   |
| I <sub>GT</sub>  | Gate trigger                         | V <sub>supply</sub> = +12 V†<br>V <sub>supply</sub> = +12 V† | R <sub>L</sub> = 10 Ω<br>R <sub>L</sub> = 10 Ω | t <sub>p(g)</sub> > 20 μs<br>t <sub>p(g)</sub> > 20 μs |     |     | 5<br>-5  |      |
|                  | current                              | $V_{supply} = -12 V^{+}$<br>$V_{supply} = -12 V^{+}$         | $R_L = 10 \Omega$<br>$R_L = 10 \Omega$         | t <sub>p(g)</sub> > 20 μs<br>t <sub>p(g)</sub> > 20 μs |     |     | -5<br>10 | mA   |

† All voltages are with respect to Main Terminal 1.

## PRODUCT INFORMATION

DECEMBER 1971 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.



## electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

| PARAMETER            |   | TEST CONDITIONS   |   |   | MIN | ТҮР     | MAX                      | UNIT |
|----------------------|---|---|---|---|-----|---------|--------------------------|------|
| V <sub>GT</sub>      | Gate trigger<br>voltage                       | $V_{supply} = +12 V \dagger$ $V_{supply} = +12 V \dagger$ $V_{supply} = -12 V \dagger$ $V_{supply} = -12 V \dagger$ | $R_{L} = 10 \Omega$ $R_{L} = 10 \Omega$ $R_{L} = 10 \Omega$ $R_{L} = 10 \Omega$ | $t_{p(g)} > 20 \ \mu s$<br>$t_{p(g)} > 20 \ \mu s$ |     |         | 2.2<br>-2.2<br>-2.2<br>3 | V    |
| V <sub>T</sub>       | On-state voltage                              | $I_{\rm T} = \pm 8.4  {\rm A}$  | I <sub>G</sub> = 50 mA  | (see Note 5)  |     |         | ±1.7                     | V    |
| I <sub>H</sub>       | Holding current                               | V <sub>supply</sub> = +12 V†<br>V <sub>supply</sub> = -12 V†  | I <sub>G</sub> = 0<br>I <sub>G</sub> = 0  | Init' I <sub>TM</sub> = 100 mA<br>Init' I <sub>TM</sub> = -100 mA   |     |         | 30<br>-30                | mA   |
| ι <sub>L</sub>       | Latching current                              | $V_{supply} = +12 V^{\dagger}$<br>$V_{supply} = -12 V^{\dagger}$  | (see Note 6)  |   |     | 4<br>-2 |                          | mA   |
| dv/dt                | Critical rate of rise of<br>off-state voltage | $V_{DRM}$ = Rated $V_{DRM}$   | I <sub>G</sub> = 0  | T <sub>C</sub> = 110°C  |     | ±20     |                          | V/µs |
| dv/dt <sub>(c)</sub> | Critical rise of<br>commutation voltage       | V <sub>DRM</sub> = Rated V <sub>DRM</sub>   | $I_{\text{TRM}} = \pm 8.4 \text{ A}$  | $T_{C} = 70^{\circ}C$   | ±2  | ±5      |                          | V/µs |

† All voltages are with respect to Main Terminal 1.

NOTES: 5. This parameter must be measured using pulse techniques,  $t_p = \le 1$  ms, duty cycle  $\le 2$  %. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.

6. The triacs are triggered by a 15-V (open-circuit amplitude) pulse supplied by a generator with the following characteristics:

 $R_G = 100 \ \Omega, \ t_{p(g)} = 20 \ \mu s, \ t_r = \le 15 \ ns, \ f = 1 \ kHz.$ 

## thermal characteristics

| PARAMETER      |   | MIN | TYP | MAX  | UNIT |
|----------------|---|-----|-----|------|------|
| $R_{\thetaJC}$ | Junction to case thermal resistance     |     |     | 2.5  | °C/W |
| $R_{\thetaJA}$ | Junction to free air thermal resistance |     |     | 62.5 | °C/W |